



#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:	I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an
Shunpei YAMAZAKI et al	envelope addressed to: Commissioner for Patents, P.O. Box 1450,
Serial No.: 10/684,936	Alexandria, VA 22313-1450, on <u>January</u> 15, 2004
Filed: October 14, 2003	Cristie m. no
Art Unit:	
For: SEMICONDUCTOR DEVICE AND METHOD OF FABRICATING THE SAME	) Date:

### INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Pursuant to 37 C.F.R. §1.97, as revised on February 4, 1992, 1135 OG 23-24, Applicant hereby calls the Examiner's attention to documents listed on the attached form, which documents may be material to the examination of this application. A copy of each of the references was submitted to the Patent Office or was cited by the Examiner in prior application serial no. 10/093,313 filed March 7, 2002, (now US patent no. 6,645,826, issued November 11, 2003) which is a divisional of the parent application serial no. 09/472,137 filed December 23, 1999, (now US patent no. 6,380,558, issued April 30, 2002) which is being relied upon for an earlier filing date under 35 U.S.C. 120 (37 C.F.R. §1.98(d)).

No inference should be drawn that the attached list sets forth a comprehensive investigation of the prior art, that any or all are pertinent to the invention, or that any apparatus disclosed is equivalent to the subject invention.

The citation of the above-discussed documents is not to be construed as an assertion that more pertinent art could not possibly be in existence. Citation of any document herein is not to be construed as an admission that any subject matter disclosed in the document is necessarily within the inventive field of endeavor, that any disclosure is necessarily prior in time to a particular date which may be relevant to the instant patent application, and/or that any disclosure is otherwise necessarily prior art with respect to the instant invention.

Applicant also respectfully reserves the right to later set forth how the instant invention is distinguished over the disclosure of any document or other art, including the disclosure of those documents discussed herein, that may be cited by the Examiner in rejecting a claim in the instant patent application.

A first office action, notice of allowance or issue fee notification has not been received in this case, so applicant does not believe that a fee is due. However, if any such fee is required, please charge our Deposit Account No. 50/1039.

Respectfully submitted,

Mark J. Murphy Registration No: 34,225

COOK, ALEX, McFARRON, MANZO, CUMMINGS & MEHLER, LTD. 200 West Adams Street Suite 2850 Chicago, Illinois 60606 (312) 236-8500

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JAN 2 0 2004  TRADEMANT OF PUBLICATIONS  CITED BY APPLICANT	Atty. Docket No. 0553-0152.02	<u>Serial No.</u> 10/684,936
	<u>Applicant</u> Shunpei YAMAZAKI et al	
	<u>Filing Date</u> October 14, 2003	Group

# U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE
	5,247,190 5,399,502 5,594,569 5,643,826 5,707,746 5,747,830 5,771,110 5,923,962 6,271,897 6,274,516 6,420,282	09/21/93 03/21/95 01/14/97 07/01/97 01/1998 05/1998 06/1998 07/13/99 08/2001 08/2001 07/2002	Friend et al Friend et al Konuma et al Ohtani et al Yaoi et al Okita Hirano et al Ohtani et al Ichikawa et al Kamei et al Batey et al			04/18/90 05/05/93 07/20/94 10/25/94

## FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	APPLICANT	English Abstract	English Trans.	FILING DATE
	WO 90/13148	11/01/90	Cambridge Research and Innovation Ltd.			04/18/90
,	JP 7-130652	05/19/95	Semiconductor Energy Lab Co. Ltd.	Х		10/29/93
	JP 7-335900	12/22/95	Semiconductor Energy Lab Co. Ltd.	Х		06/09/94
	JP 8-078329	03/22/96	Semiconductor Energy Lab Co. Ltd.	Х		09/05/94
	JP 10-092576	04/10/98	Cambridge Display Technology Ltd.	Х		04/18/97
	JP 10-135468	05/22/98	Semiconductor Energy Lab Co. Ltd.	Х		10/24/96
	JP 10-135469	05/22/98	Semiconductor Energy Lab Co. Ltd.	X		10/24/96
	JP 10-247735	09/14/98	Semiconductor	Х		03/03/97
			Energy Lab Co. Ltd.			



# OTHER PRIOR ART - NON-PATENT LITERATURE DOCUMENTS (Including Author, Title, Date, Pertinent Pages)

- 1) YEH, J.L. et al, "Structural and Optical Properties of Amorphous Silicol Oxynitride," J. Appl. Phys., vol. 79, no. 2, pp. 656-663, January 15, (1996).
- 2) INUI, S. et al, "Thresholdless Antiferroelectricity in Liquid Crystals and its Application to Displays," J. Mater Chem., vol. 6, no. 4, pp. 671-673, (1996).
- 3) YOSHIDA, T. et al, "A Full-Color Thresholdless Antiferroelectric LCD Exhibiting Wide Viewing Angle with Fast Response Time," SID 97 Digest, pp. 841-844, (1997).
- 4) FURUE, H. et al, "Characteristics and Driving Scheme of Polymer-Stabilized Monostable FLCD Exhibiting Fast Response Time and High Contrast Ratio with Gray-Scale Capability," SID 98 Digest, pp. 782-785 (1998).
- 5) TERADA et al, "Half-V Switching Mode FLCD," Proceedings of the 46th Applied Physics Association Lectures, 28p-V-8, p. 1316, March, (1999).
- 6) SCHENK, H. et al, "Polymers for Light Emitting Diodes," **EURODISPLAY** '99 Proceedings of the 19th International Display Research Conference, Berlin, Germany, September 6-9, pp. 33-37 (1999).
- 7) YOSHIHARA, T. et al, "Time Division Full Color LCD by Ferroelectric Liquid Crystal," **EKISHO**, Vol 3, no. 3, pp. 190-194, (1999).

EXAMINER:

DATE CONSIDERED:

\*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP form. Draw line through citation if not in conformance and not considered. Include a copy of this form with the next communication to applicant.

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& TRADEMA			Atty. Docket No. 0553-0152.02	<u>Serial No.</u> 10/684,936			
LIST OF PUBLICATIONS CITED BY APPLICANT		<u>Applicant</u> Shunpei YAMAZAKI et al					
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*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE	
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λ. .>	JP 56-111258  JP 58-164268  JP 64-35961  JP 1-276672  JP 5-55581	09/02/81 09/29/83 02/07/89 11/07/89 03/05/93	Chou-L.S.I. Gijutsu Kenkyu Kumiai K.K. Suwa-Seikosha Richo Co., Ltd. Seiko Corp. Semiconductor Energy Lab Co. Ltd.		X X X X X	01/07/80 03/25/82 07/30/87 04/27/88 08/26/91	
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